

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
30V	280mΩ@4.5V	0.75A
	380mΩ@2.5V	

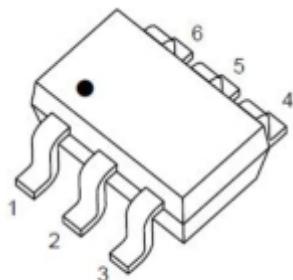
Feature

- Surface Mount Package
- N-Channel Switch with Low RDS(on)
- Operated at Low Logic Level Gate Drive
- ESD Protected: 2KV

Applications

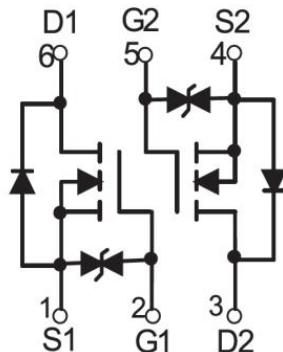
- Load/Power Switching
- Motor Control
- Power Management
- DC-DC Converters

Package



SOT-363

Circuit diagram



Marking



3002 =Device Code

Absolute maximum ratings

($T_a=25^\circ\text{C}$ unless otherwise noted)

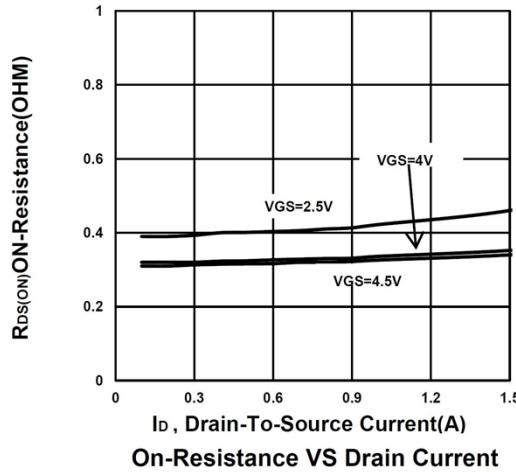
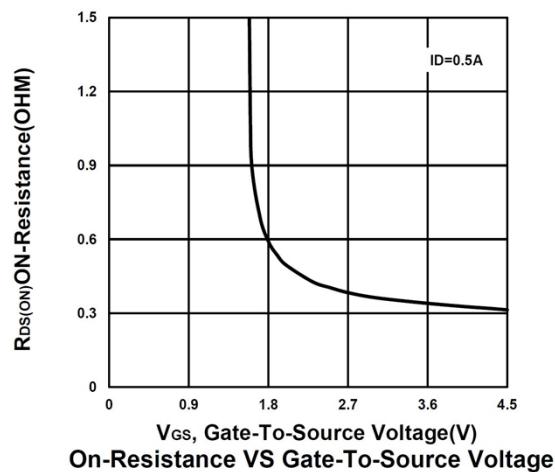
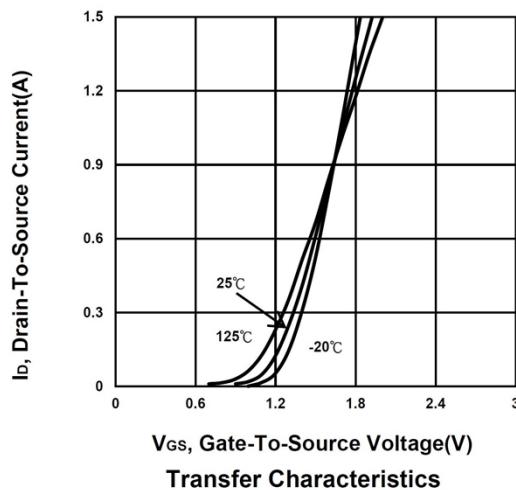
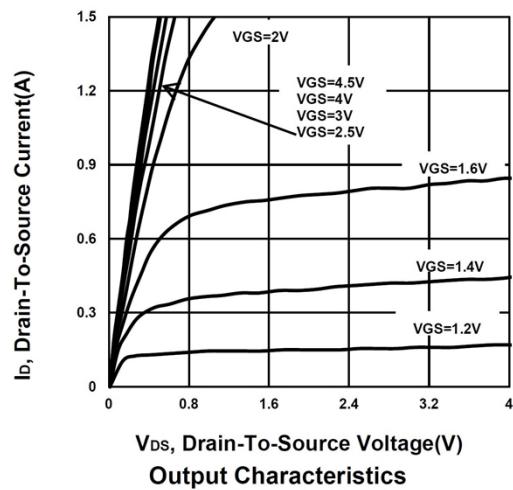
Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current	I_D	0.75	A
Pulsed Drain Current	I_{DM}	3	A
Power Dissipation	P_D	0.29	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	431	$^\circ\text{C}/\text{W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55~+150	$^\circ\text{C}$

Electrical characteristics

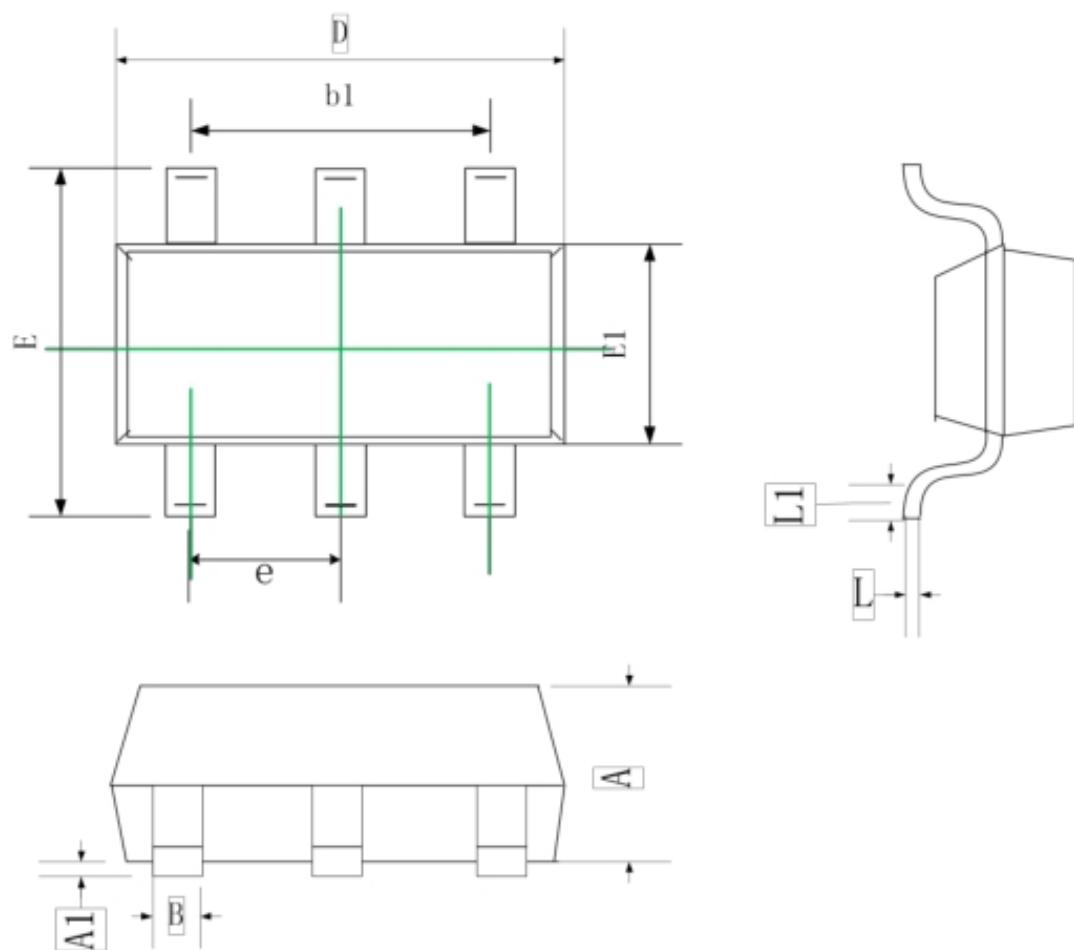
($T_A=25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$\text{BV}_{(\text{BR})\text{DSS}}$	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	30			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 24\text{V}, V_{GS} = 0\text{V}$			1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 12\text{V}, V_{DS} = 0\text{V}$			± 10	μA
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	0.6	1.0	1.3	V
Drain-source on-resistance	$R_{DS(\text{on})}$	$V_{GS} = 4.5\text{V}, I_D = 0.5\text{A}$		0.28	0.40	Ω
		$V_{GS} = 2.5\text{V}, I_D = 0.3\text{A}$		0.38	0.55	
Dynamic Characteristics						
Input capacitance	C_{iss}	$V_{DS} = 15\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$		50		pF
Output capacitance	C_{oss}			16		
Reverse transfer capacitance	C_{rss}			9		
Switching Characteristics						
Total gate charge	Q_g	$V_{GS} = 4.5\text{V}, V_{DS} = 15\text{V}, I_D = 1\text{A}$		1		nC
Gate-source charge	Q_{gs}			0.26		
Gate-drain charge	Q_{gd}			0.23		
Turn-on Delay Time	$T_{d(\text{on})}$	$V_{GS} = 4.5\text{V}, V_{DS} = 15\text{V}, I_D = 500\text{mA}, R_{\text{GEN}} = 6\Omega$		17		nS
Turn-on Rise Time	T_r			32		
Turn-Off Delay Time	$T_{d(\text{off})}$			92		
Turn-Off Fall Time	t_f			46		
Source-Drain Diode characteristics						
Body Diode Voltage	V_{SD}	$I_s = 0.5\text{A}, V_{GS} = 0\text{V}$			1.2	V

Typical Characteristics



SOT-363 Package Information



Symbol	Dimensions In Millimeters	
	Min.	Max.
A	0.90	1.00
A1	0.00	0.10
B	0.10	0.30
b1		1.30
D	1.80	2.20
E	2.00	2.20
E1	1.15	1.35
e	0.65 TYP.	
L	0.10	0.25
L1	0.15	0.4